

LB1862M, LB1962M

Allowable Operating Conditions at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Power supply voltage	V _{CC}		3.8 to 16.8	V
ST input High level voltage	ST _H		3 to 14	V
ST input Low level voltage	ST _L		-0.3 to +0.4	V
Hall input common mode voltage	V _{ICM}		0.2 to V _{CC} -1.5	V

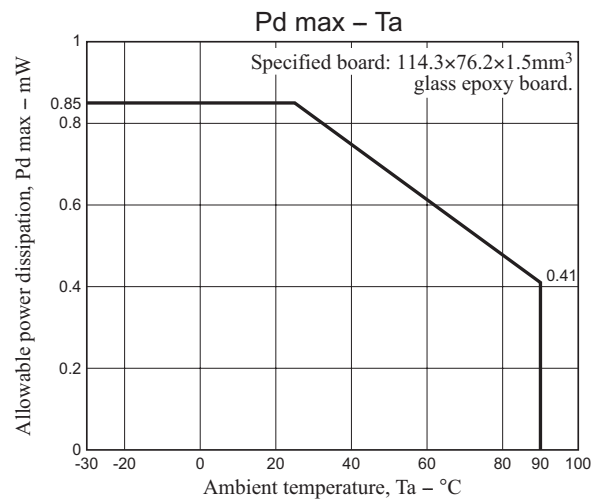
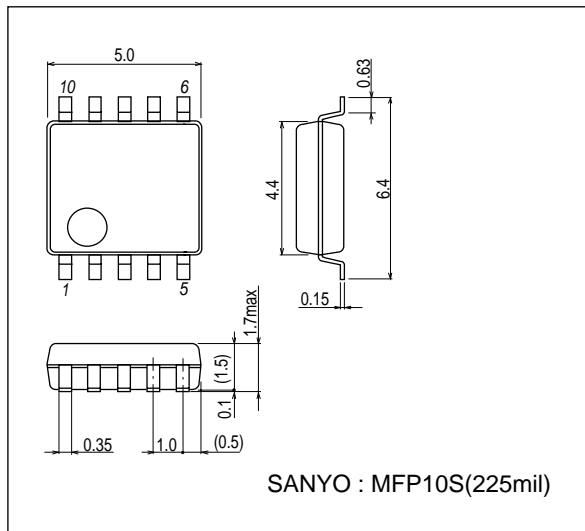
Electrical Characteristics at Ta = 25°C, V_{CC} = 5V

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Current drain	I _{CC}	In drive mode (CT = "L", ST = "L")		6.5	9.1	mA
		In lockup protection mode (CT = "H", ST = "L")		2.2	3.1	mA
		In standby mode (ST = "H")		110	150	μA
Lockup detection capacitor charge current	I _{CT1}		1.9	2.8	3.7	μA
Capacitor discharge current	I _{CT2}		0.32	0.46	0.60	μA
Capacitor charge/discharge current ratio	R _{CT}	R _{CT} = I _{CT1} /I _{CT2}	5.0	6.0	7.0	
CT charge voltage	V _{CT1}		2.55	2.75	2.95	V
CT discharge voltage	V _{CT2}		1.6	1.8	2.0	V
Output Low level voltage	V _{OL}	I _O = 200mA		0.2	0.3	V
Output High level voltage	V _{OH}	I _O = 200mA	3.9	4.1		V
Hall input sensitivity	V _{HN}	Zero peak value (Including offset and hysteresis)		7	15	mV
RD/FG output pin Low voltage	V _{RD(FG)}	I _{RD(FG)} = 5mA		0.1	0.3	V
RD/FG output pin leakage current	I _{RD(FG)}	V _{RD(FG)} = 15V			30	μA
HB output Low voltage	V _{HBL}	I _{HB} = 5mA		1.0	1.3	V
ST pin input current	I _{ST}	V _{ST} = 5V		75	100	μA

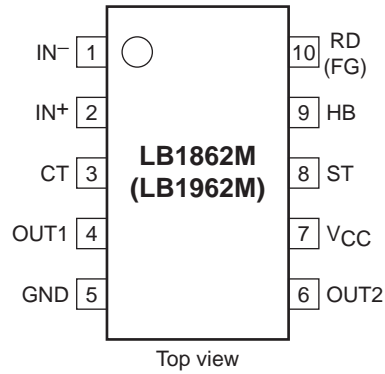
Package Dimensions

unit : mm (typ)

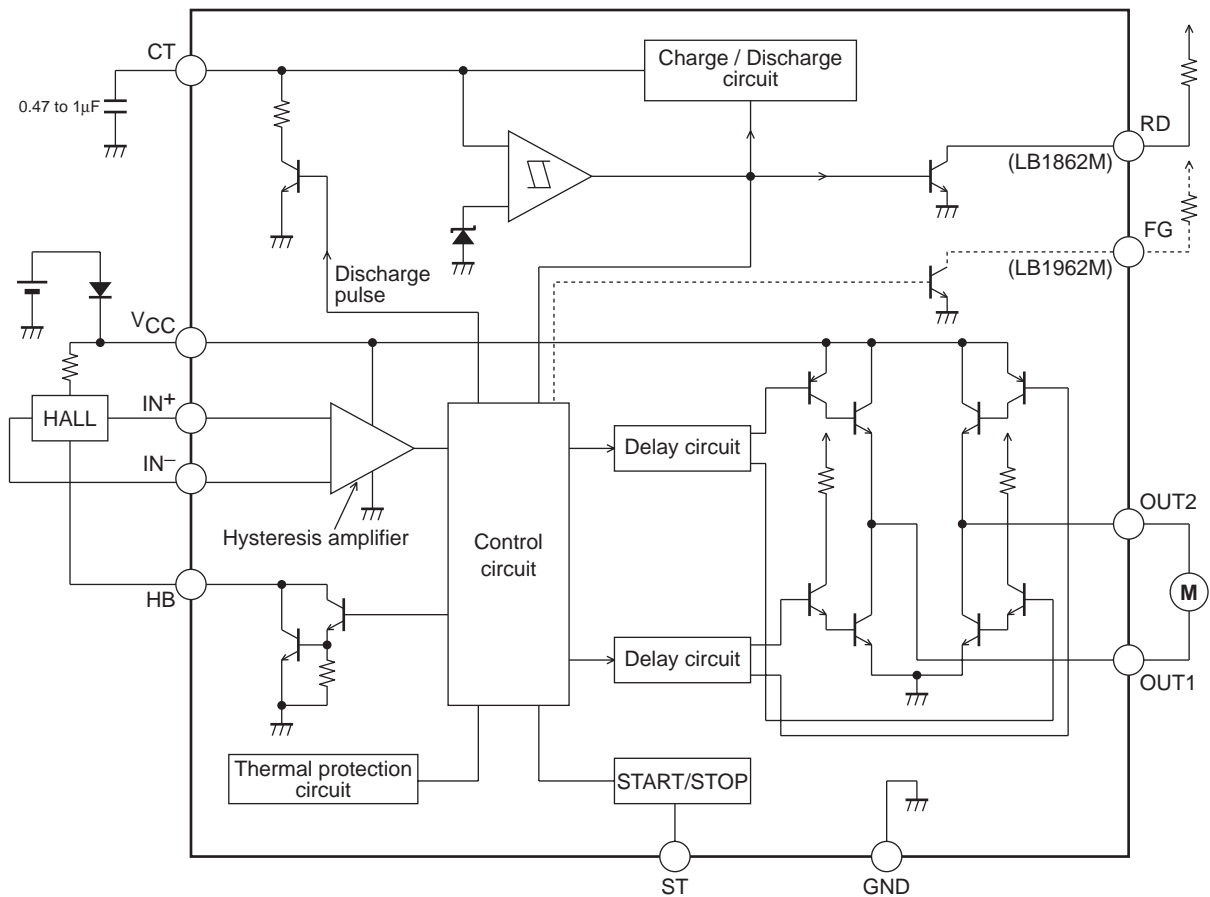
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Pin Assignment



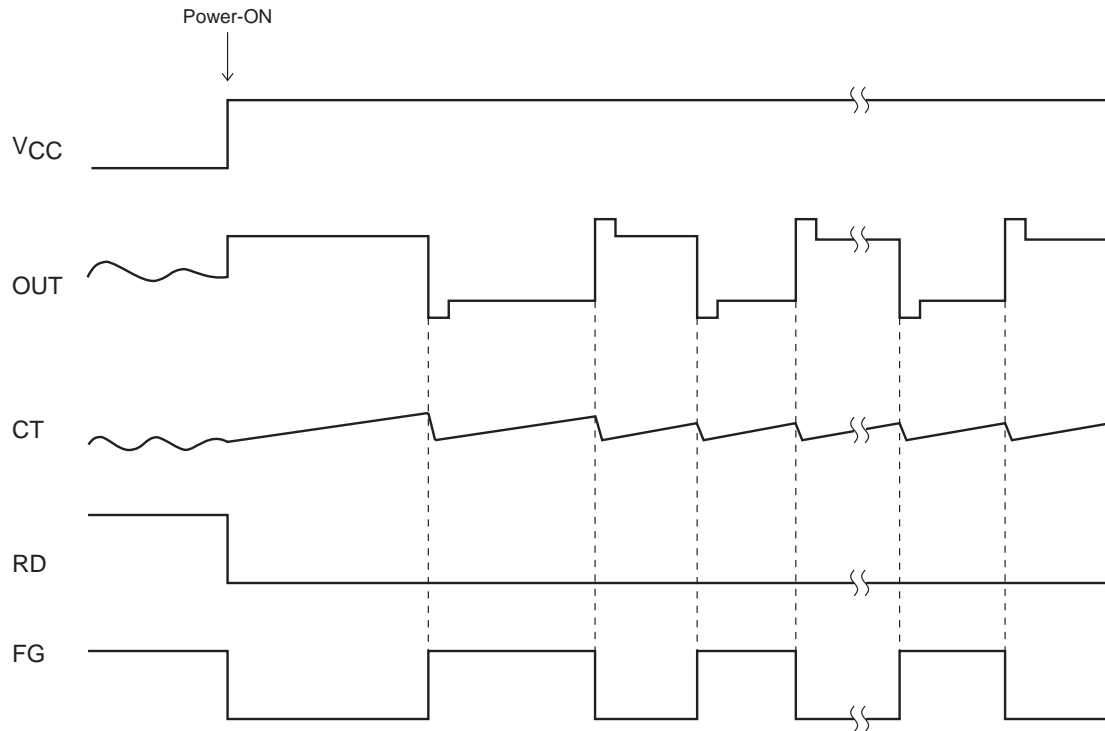
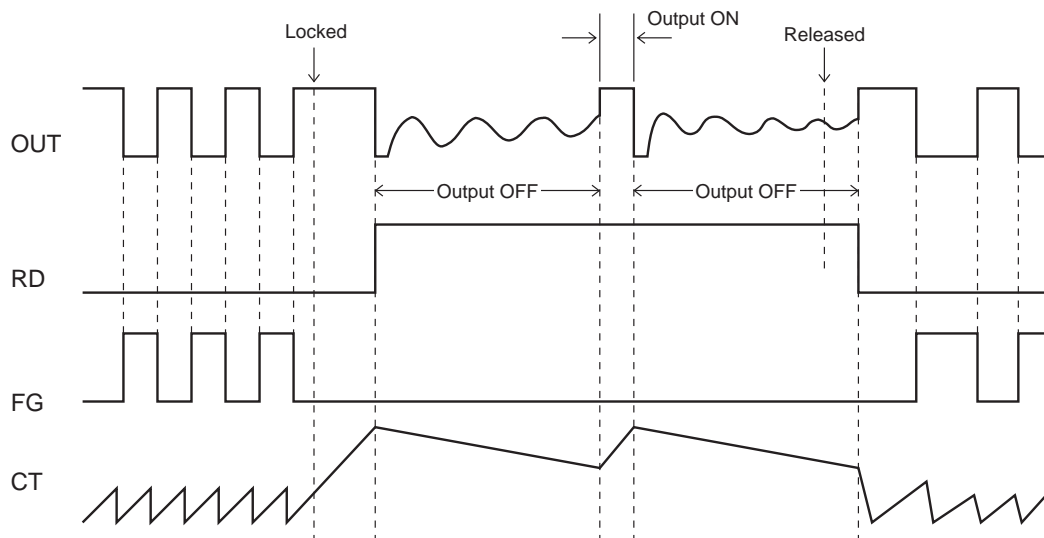
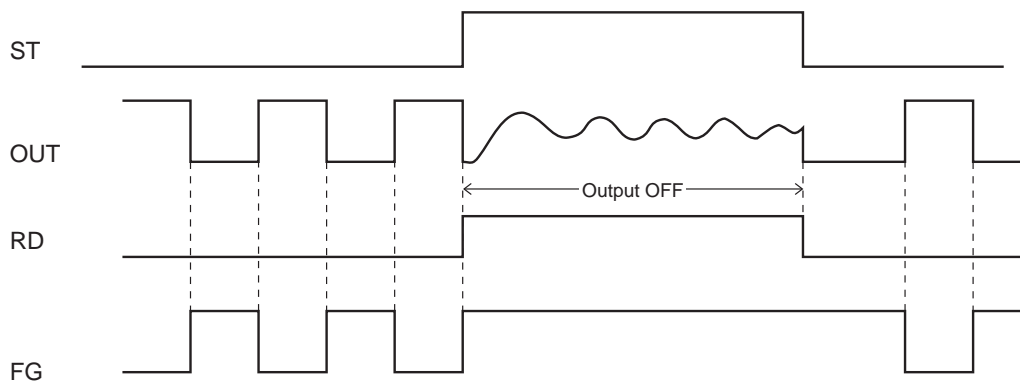
Block Diagram



Truth Table

ST	IN-	IN+	CT	OUT1	OUT2	RD	FG	HB	Mode
H	-	-	-	OFF	OFF	OFF	OFF	OFF	Standby
L	H	L	L	H	L	L	L	L	Rotating
	L	H		L	H		H		
	-	-	H	OFF	OFF	OFF	-	L	Lockup protection activated

Latch-type RD output is Low during rotation and High during stop.

Startup**Lockup protection/automatic recovery****Start/stop**

Design Reference**(1) V_{CC} pin**

Power supply pin for control block and motor drive.

Accepts a wide operation voltage range from 3.8 to 16.8V, for 5V/12V dual power supply support.

(2) OUT1, OUT2 pins

Single-phase coil output pins.

Bipolar drive output with upper side inverted and lower side single output. Built-in regenerative circuit regenerates kickback current between lower side NPN outputs when a diode is used for protection against reverse connection.

(3) IN⁻, IN⁺ pins

Hall input signal pins

The Hall signal is amplified into a square wave by the Hall amplifier with hysteresis characteristics of $\pm 3.5\text{mV}$ (typ.).

The Hall input signal amplitude should be 70mV or more.

(4) CT pin

This pin serves for connecting a capacitor between CT and GND.

The capacitor determines the characteristics of the built-in lockup protection circuit for preventing coil burnout in the case of motor restraint. Once normal motor load is restored, the automatic recovery circuit resets itself.

Changing the capacitance alters the lockup detection time.

When a 0.47 mF capacitor is connected between CT and GND

Lockup detection time : approx. 0.5s

Lockup protection time/automatic recovery time : approx. 0.16s (output ON)

approx. 1s (output OFF)

When not using lockup protection function, this pin should be connected to ground.

(5) RD pin (LB1862M)

Open-collector output pin that is Low during rotation and OFF when lockup is detected.

The output is a latch type which stays OFF also when the automatic recovery circuit has restored drive mode unless the rotation actually resumes.

(6) FG pin (LB1962M)

Open-collector output pin for rotation frequency detection.

When IN⁻ = High and IN⁺ = Low, then FG = Low

When IN⁻ = Low and IN⁺ = High, then FG = High

(7) ST pin and HB pin

ST pin : When input to this pin is High, motor drive is stopped (OUT is high impedance).

At this time, RD output indicates lockup protection mode OFF.

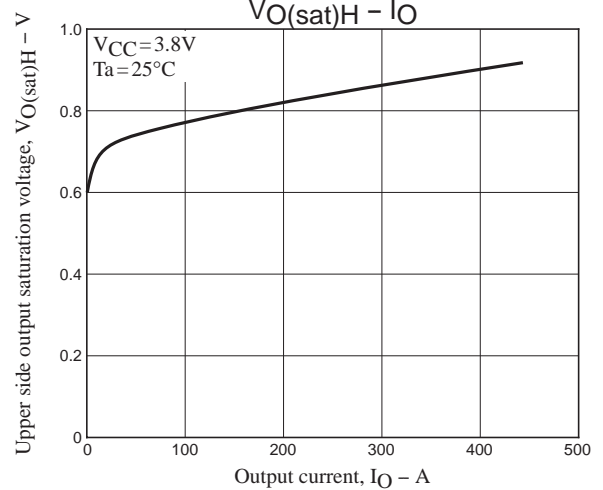
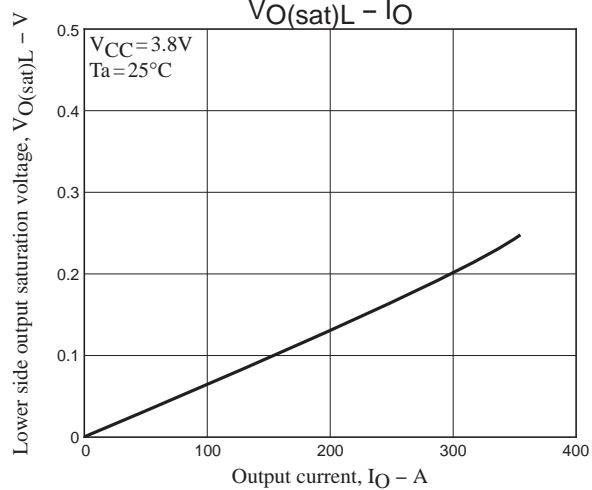
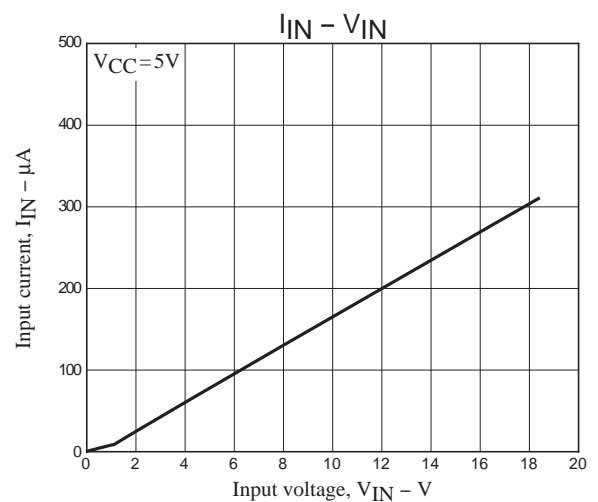
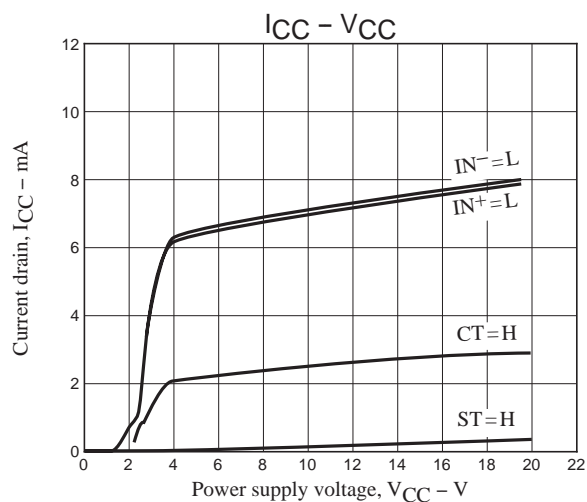
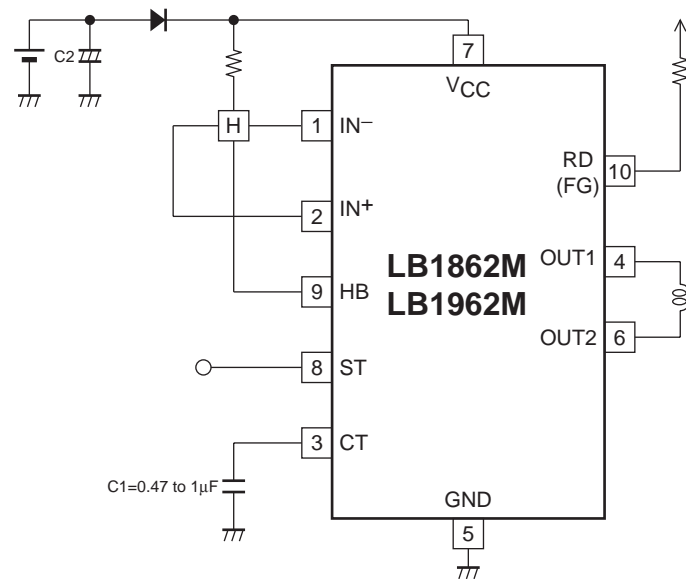
HB pin : Hall bias switching pin. At ST pin High input, Hall bias is switched to reduce current drain in fan standby mode.

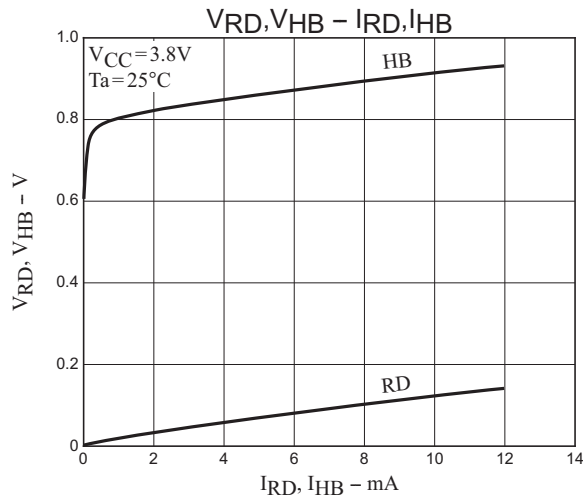
If not used, both pins should be open.

(8) Thermal protection circuit

When internal temperature T_j of IC reaches 180°C, output current limiter is activated to protect against damage.

Application Circuit Example





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